

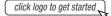
### Vishay General Semiconductor

# **Dual High Voltage Trench MOS Barrier Schottky Rectifier**

Ultra Low  $V_F = 0.50 \text{ V}$  at  $I_F = 5 \text{ A}$ 



#### **DESIGN SUPPORT TOOLS**

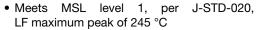




PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	2 x 30 A			
$V_{RRM}$	170 V			
I <sub>FSM</sub>	210 A			
V <sub>F</sub> at I <sub>F</sub> = 30 A	0.72 V			
T <sub>J</sub> max.	175 °C			
Package	D <sup>2</sup> PAK (TO-263AB)			
Circuit configuration	Common cathode			

#### **FEATURES**

- Trench MOS Schottky technology
- · Low forward voltage drop, low power losses
- · High efficiency operation





 Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

#### TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

#### **MECHANICAL DATA**

Case: D<sup>2</sup>PAK (TO-263AB)

Molding compound meets UL 94 V-0 flammability rating

Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

<b>MAXIMUM RATINGS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER			VB60170G	UNIT		
Maximum repetitive peak reverse voltage		$V_{RRM}$	170	V		
Maximum average forward rectified current	per device	I <sub>F(AV)</sub>	60	Α		
(fig. 1)	per diode		30			
Peak forward surge current 8.3 ms single half sine-wave supe	I <sub>FSM</sub>	210	Α			
Voltage rate of change (rated V <sub>R</sub> )		dV/dt	10 000	V/µs		
Operating junction and storage temperature range		$T_J$ , $T_{STG}$	-40 to +175	°C		

<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Instantaneous forward voltage per diode	I <sub>F</sub> = 5 A		V <sub>F</sub> <sup>(1)</sup>	0.65	-	V	
	I <sub>F</sub> = 15 A	T <sub>A</sub> = 25 °C		0.78	-		
	I <sub>F</sub> = 30 A			0.87	1.02		
	I <sub>F</sub> = 5 A	T <sub>A</sub> = 125 °C		0.50	-		
	I <sub>F</sub> = 15 A			0.62	-		
	I <sub>F</sub> = 30 A			0.72	0.80		
Reverse current per diode	V <sub>R</sub> = 136 V	T <sub>A</sub> = 25 °C	I <sub>R</sub> <sup>(2)</sup>	1.5	-	μΑ	
		T <sub>A</sub> = 125 °C		2.5	-	mA	
	V <sub>R</sub> = 170 V	T <sub>A</sub> = 25 °C		-	450	μΑ	
		T <sub>A</sub> = 125 °C		5	50	mA	

#### Notes

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 20 ms



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THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)					
PARAMETER		SYMBOL	VB60170G	UNIT	
Typical thermal resistance	per diode	$R_{ hetaJC}$	1.0	°C/W	
	per device		0.7	C/W	

ORDERING INFORMATION (Example)						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
TO-263AB	VB60170G-E3/4W	1.38	4W	50/tube	Tube	
TO-263AB	VB60170G-E3/8W	1.38	8W	800/reel	Tape and reel	

### **RATINGS AND CHARACTERISTICS CURVES** ( $T_A = 25$ °C unless otherwise noted)

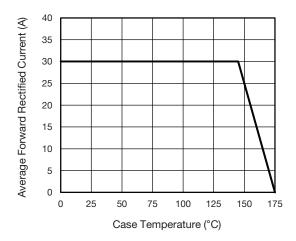


Fig. 1 - Maximum Forward Current Derating Curve

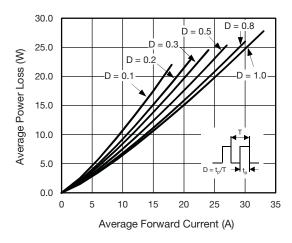


Fig. 2 - Forward Power Loss Characteristics Per Diode

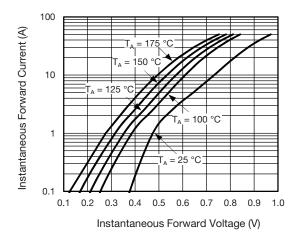


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

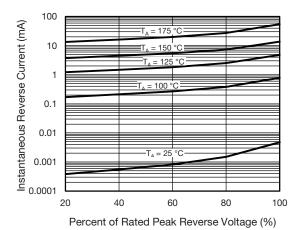


Fig. 4 - Typical Reverse Characteristics Per Diode



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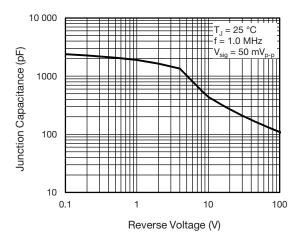


Fig. 5 - Typical Junction Capacitance Per Diode

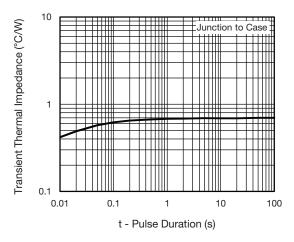
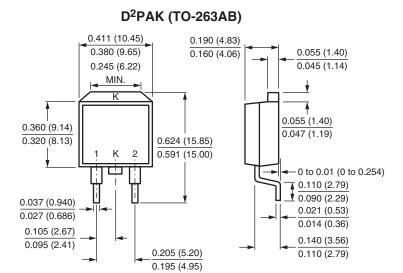
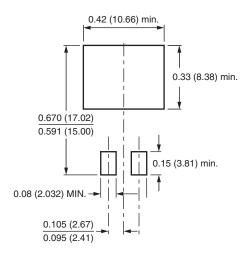


Fig. 6 - Typical Transient Thermal Impedance Per Diode

#### PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



### **Mounting Pad Layout**





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